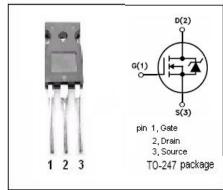


# isc N-Channel MOSFET Transistor

## IXFH20N85X

#### FEATURES

- · With TO-247 packaging
- With low gate drive requirements
- · Easy to drive
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



### APPLICATIONS

Switching applications



### • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	850	V
V <sub>GSS</sub>	Gate-Source Voltage	±30	V
I <sub>D</sub>	Drain Current-Continuous	20	А
I <sub>DM</sub>	Drain Current-Single Pulsed	50	А
P <sub>D</sub>	Total Dissipation	540	W
Tj	Operating Junction Temperature	-55~150	$^{\circ}\!\mathbb{C}$
T <sub>stg</sub>	Storage Temperature	-55~150	${\mathbb C}$

# mm MIN MAX 19.80 20.20 15.40 15.80 C 4.90 D 0.90 E 1.40 F 1.90 G 10.80 11.00 2.40 H 2.60 J 0.50 0.70 19.50 20.50 3.90 3.30 U 5.20 2.90

### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	0.23	°C/W



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#### **ELECTRICAL CHARACTERISTICS**

T<sub>c</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 1mA	850			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; I <sub>D</sub> =2.5mA	3.5		5.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =10A			330	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> = 0V			±0.1	μА
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 650V; V <sub>GS</sub> = 0V;@Tc=25°C Tc=125°C			25 1500	μА
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> =20A, V <sub>GS</sub> = 0 V			1.4	V

### **NOTICE:**

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